L Number	Hits	Search Text	DB	Time stamp
2	433	430/11,5,30.ccls. and lens and	USPAT	2004/09/07 18:00
_		lithographic and mask	001111	2001,03,0. 10100
1	42	430/11,5,30.ccls. and (lens near10	USPAT	2004/09/07 18:54
-		semiconductor) and lithographic and mask	OSTAI	2004/03/07 10.54
3	1	430/11,5,30.ccls. and (lens near10	USPAT	2004/09/07 18:01
		semiconductor) and lithographic and mask	OSFAI	2004/03/07 18.01
		and (mask same pull\$1back)		
4	17	430/296,311,320,321.ccls. and (lens near10	USPAT	2004/09/07 18:56
•	1,	semiconductor) and lithographic and mask	OSFAI	2004/03/07 18.30
5	3	257/432,98.ccls. and (lens near10	USPAT	2004/09/07 18:56
	,	semiconductor) and lithographic and mask	OSTAT	2004/03/07 18.50
	3733		USPAT	2004/09/01 21:59
	3733	BOETTIGER.in. and ULRICH	USPAT	2004/09/01 21:35
_	5	(BOETTIGER.in. and ULRICH) and lens	USPAT	2004/09/01 21:25
	4	BOETTIGER.in. and ULRICH	US-PGPUB	2004/09/01 21:25
_	178			
	1/6	((lens near material) and lens.ab.) and wafer	USPAT	2004/09/01 21:59
_	109	((lens near material) and lens.ab.) and	USPAT	2004/09/02 18:31
	109	(wafer with lens)	USFAI	2004/09/02 18:31
_	832	lens near2 semiconductor	USPAT	2004/09/02 18:31
i _	279	lens near semiconductor	USPAT	2004/09/02 18:31
_	143	(lens near semiconductor) and lens.ab.	USPAT	2004/09/02 20:27
_	63	(lens near semiconductor) and mask	USPAT	2004/09/02 21:32
	24	(lens near semiconductor) and mask	USPAT	2004/09/02 18:32
-	24	mask	USPAI	2004/09/02 19:12
_	51	(lens with semiconductor) and lens.ab. and	USPAT	2004/09/02 19:12
	J.	mask and micro\$1lens	OSFAI	2004/03/02 13.12
l <u> </u>	16	(lens with semiconductor) and lens.ab. and	USPAT	2004/09/02 19:12
	10	(mask same micro\$1lens)	USFAI	2004/03/02 13.12
<u>-</u>	40	lens near semiconductor and method and	USPAT	2004/09/02 21:32
	10	(coat\$3 and expos\$3 and remov\$4)	OSTAT	2004/03/02 21:32
_	40	(lens near semiconductor) and method and	USPAT	2004/09/02 20:33
	- 10	(coat\$3 and expos\$3 and remov\$4)	OSTAT	2004/03/02 20:55
_	9	(lens near semiconductor) and lens.ab. and	USPAT	2004/09/02 21:33
		lithographic and mask	JULAI	2004/05/02 21.55
_	27	(lens near10 semiconductor) and lens.ab.	USPAT	2004/09/02 21:33
	2,	and lithographic and mask and array	331731	2004/05/02 21.55
	1	359/618,621,623.ccls. and (lens near10	USPAT	2004/09/03 13:27
[_	semiconductor) and lens.ab. and	551111	2001,03,03 13.2,
		lithographic and mask and array		
_	18	("4326800" "4490039" "5233174"	USPAT	2004/09/02 21:42
	10	"5463649" "5493391" "5539718"	051711	2004/05/02 21:42
		"5610897" "5825476" "5828455"		
		"5864381" "5912731" "5936720"		
		"5936739" "5939716" "5978085"		
		"6052180" "6130419" "6184974").PN.		
-	2	430/321,396.ccls. and (lens near10	USPAT	2004/09/03 13:27
	_	semiconductor) and lens.ab. and		
		lithographic and mask and array	1	
-	0	430/1,2,4,5,6.ccls. and (lens near10	USPAT	2004/09/07 17:59
	-	semiconductor) and lens.ab. and		
		lithographic and mask and array		
	_		L	I